## EE1050 Final given: Spring 01

1. (20 pts) The following questions are similar to what you might see on the FE exam. You don't have to show your work here, in fact use scratch paper if you need more room.
a) Find $\mathrm{I}_{1}$ in amps.
(A) 3
(B) 4.2
(C) 12
(D) 15
(E) 20.6

b) What is the average power dissipated by an electric heater with a resistance of $50 \Omega$ and drawing a current of $20 \sin (30 t) \mathrm{A}$ ?
(A) 4 kW
(B) 10 kW
(C) 14.14 kW
(D) 20 kW
(E) 50 kW
c) What is the correct phasor (polar) expression for the effective current in the graph shown?
(A) $35 \underline{/-90}{ }^{\circ} \mathrm{A}$
(B) $35 / 90^{\circ} \mathrm{A}$
(C) $35 \underline{\boxed{270}}{ }^{\circ} \mathrm{A}$
(D) $50 \underline{/-90^{\circ} \mathrm{A}}$
(E) $50 / 90{ }^{\circ} \mathrm{A}$

Notes: By "effective", they mean RMS.


The phase angle is relative to the voltage.
d) How much power is dissipated by the $1 \mathrm{k} \Omega$ resistor?
(A) 0 W
(B) 0.001 W
(C) 0.1 W
(D) 10 W
(E) 10 MW

e) What is the equivalent impedance when the circuit shown is connected to a 120 V 60 Hz source?
(A) $120 \Omega / 83{ }^{\circ}$
(B) $120 \Omega / 90^{\circ}$
(C) $732 \Omega \underline{l-30^{\circ}}{ }^{\circ}$
(D) $991 \Omega /-5.7^{\circ}$

(E) $1206 \Omega \underline{/-90}{ }^{\circ}$

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2. (13 pts) Use the method of superposition to find the current through $R_{1}$, $\left(I_{R 1}\right)$. Be sure to clearly show and circle your intermediate results.

3. (23 pts)
a) Find and draw the Thévenin equivalent of the circuit shown. The load resistor is $R_{L}$.
b) Find and draw the Norton equivalent of the same circuit.
c) Find the load voltage using either your Thévenin or Norton equivalent circuit.
d) Find the power dissipated in the load resistor.

4. (18 pts) The switch has been in the open position for a long time and is closed (as shown) at time $t=0$. Find the initial and final conditions and write the full expression for $\mathrm{i}_{\mathrm{L}}(\mathrm{t})$, including all the constants that you find.
When the switch is closed this circuit is very similar to the circuit in problem 3. Use your answers to that problem here if you can.

Don't panic, this is just a first order system.

5. (24 pts)
a) Find $V_{\text {in }}$ in polar form.
b) Find $I_{T}$.
c) Circle 1 :
i) The source current leads the source voltage
ii) The source voltage leads the source current
d) By how much? I.E. what is the phase angle between the voltage and current?

6. (16 pts)
a) Find the differential equation for $v_{R}$, the voltage across the resistor.
b) Find the characteristic equation.


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7. (22 pts) In the circuit shown, use the 0.7 V -drop model for the silicon diode.
a) Assume that diode $D_{1}$ conducts.

Assume that diode $\mathrm{D}_{2}$ does not conduct.
Find $\mathrm{I}_{\mathrm{R} 1}, \mathrm{I}_{\mathrm{R} 2}, \mathrm{~V}_{\mathrm{R} 2}$, and $\mathrm{V}_{\mathrm{R} 3}$ based on these assumptions.
$\mathrm{I}_{\mathrm{R} 1}=$ $\qquad$
$\mathrm{I}_{\mathrm{R} 2}=$ $\qquad$
$\mathrm{V}_{\mathrm{R} 2}=$ $\qquad$
$\mathrm{V}_{\mathrm{R} 3}=$ $\qquad$

b) Was the assumption about $\mathrm{D}_{1}$ correct?
yes no
How do you know?
(circle one)
c) Was the assumption about $\mathrm{D}_{2}$ correct?
yes no

How do you know?
(circle one)
d) If you have to make new assumptions based on your answers to b) and c), which of the following need to be recalculated.

$$
\begin{array}{lcc}
\mathrm{I}_{\mathrm{R} 1} & { }^{\mathrm{I}} \mathrm{R} 2 & \mathrm{~V}_{\mathrm{R} 2} \\
\text { (circle any number) }
\end{array} \quad{ }^{\mathrm{V}} \mathrm{~V}_{\mathrm{R} 3}
$$

8. ( 14 pts ) The voltage waveform shown below (dashed line) is applied to the circuit shown at right. On the same graph, accurately draw the output voltage you expect to see across the $35 \Omega$ resistor. Use the constant-voltage-drop model for the silicon diode. Label times and voltage levels at all points where your output changes direction.



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9. (30 pts) Fill in the blanks in the circuit. You may neglect $I_{B}$ 's effect on $I_{E}$, but do not neglect it on the base side of the transistor.
b) Is the transistor operating in the active region?

Yes No
(Circle one)
Show your evidence.
c) What is the value of $\beta$ of this transistor?
d) If we neglect $I_{B}$ and use the values of $R_{1}$ and $R_{2}$ above to calculate $V_{B}$, what do you get?
e) Considering only $\mathrm{I}_{\mathrm{C}}$ and $\mathrm{V}_{\mathrm{CE}}$, how much power
 does this transistor dissipate or contribute?
f) If the $v_{s}$ signal were applied at the base, an AC signal would also appear at the collector. How much larger would it be. (Voltage gain).
10. Do you want your grade and scores posted on my door and on the internet?

Yes No
(Circle one)
If your answer is yes, then provide some sort of alias or password: $\qquad$
The grades will be posted on my door in alphabetical order under the alias that you provide here. I will not post grades under your real name. The internet version will be an excel spreadsheet which you can download. Both will show all your homework, lab, and exam scores.
Answers
1.a) C
b) $B$
c) A
d) $A$
e) $C$
2. $25 \mathrm{~mA}-20 \mathrm{~mA}=5 \mathrm{~mA}$

## 3.a)

$$
\mathrm{R}_{\mathrm{Th}}:=400 \cdot \Omega
$$

b)
$\mathrm{R}_{\mathrm{N}}:=400 \cdot \Omega$
c) 2.4 V

d) 7.2 mW
4) $9 \cdot \mathrm{~mA}+(11 \cdot \mathrm{~mA}) \cdot \mathrm{e}^{\frac{\mathrm{t}}{0.4 \cdot \mathrm{~ms}}}$
5.a) $10 \mathrm{~V} / 36.9^{\circ}$
b) $314 \mathrm{~mA} / 43.0^{\circ}$
c) current leads voltage
d) $6.16^{\circ}$
6.a) $\frac{d^{2}}{d t^{2}} v_{\text {in }}(t)+\frac{1}{L \cdot C} \cdot v_{\text {in }}(t)$
$=\frac{d^{2}}{d t^{2}} v R^{(t)}+\frac{1}{R \cdot C} \cdot \frac{d}{d t} v_{R}(t)+\frac{1}{L \cdot C} \cdot v R^{(t)}$
b) $\mathrm{s}^{2}+\frac{1}{\mathrm{R} \cdot \mathrm{C}} \cdot \mathrm{s}+\frac{1}{\mathrm{~L} \cdot \mathrm{C}}=0$
7.a) $5 \mathrm{~mA}, 10 \mathrm{~mA}, 1 \mathrm{~V}, 0.3 \mathrm{~V}$
b) yes, $I_{D 1}>0$
c) $\mathrm{no}, \mathrm{V}_{\mathrm{D} 2}>0.7 \mathrm{~V}$
d) all but $\mathrm{I}_{\mathrm{R} 1}$
9.a) $\mathrm{V}_{\mathrm{B}}=2.8 \mathrm{~V}, \mathrm{I}_{\mathrm{R} 1}=1.015 \mathrm{~mA}, \mathrm{I}_{\mathrm{R} 2}=0.933 \mathrm{~mA}$, $R_{2}=3 k \Omega, R_{E}=171 \Omega, V_{C E}=6.15 \mathrm{~V}, R_{C}=630 \Omega$
b) yes, VCE $>0.2 \mathrm{~V}$
c) 150
d) 3 V
e) 75.6 mW
f) 3.69

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